

GPON ONU Triplexer Optical Subassembly with Pigtail

Description

LN0311 series has a 1310(TX)/1490nm(RX)/1550nm(RX) triplexer optical subassembly (Tri-OSA) for GPON ONU and CATV transmission application .

This module contains a 1310nm MQW DFB laser diode as transmitter, a InGaAs/InP PIN and a InGaAs/InP APD as receiver, two edge filter are integrated into a small housing to separate the wavelengths 1310nm 1490nm and 1550nm.

The DFB with an InGaAs monitor PD, it can be used with appropriate feedback control circuitry to set optimal power level for each FP laser, As the current changed above the threshold, the optical power will change accordingly.

The PIN chip has a photosensitivity area diameter of 80um with a InGaAs planar structure, it can be receive the optical signal and convert to analog signal.

The APD-TIA transduces incident light into optical current with high efficiency. The TIA converts the current signal into a digital voltage signal with a very low input noise.

The products has single mode type fiber with a SC/APC optical connector can be selected.

Features

- 1310 nm burst-mode transmitter with uncooled DFB-LD
- 1490nm continuous-mode receiver with High sensitive APD-TIA
- 1550nm PIN diode receiver with low noise and low distortion,
- Low optical crosstalk
- High optical power output up to 1.8mW
- Suitable for ITU G 984.5 standard
- Compact and economical
- operating temperature range: -10°C to 85°C

Application

- PON ONU system application
- Suitable for CATV application



Absolute Maximum Ratings^[1]

Parameter	Symbol	Min	Max	Units	Notes
Reverse Voltage(LD)	V _{RL}		2	V	
Forward Current(LD)	IFL		120	mA	
Reverse Voltage(MPD)	VRMP		10	V	
Forward Current(MPD)	IFMP		2	mA	
Reverse Voltage(PIN)	VRP		10	V	
Forward Current(PIN)	IR		2	mA	
Reverse Voltage(APD)	VRA		Vbr	V	
Reverse Current(APD)	IA		2	mA	
Supply Voltage (TIA)	VCC	-0.4	+4	V	
Operating Temperature [1]	Tc	-10	+85	°C	Case temperature
Storage Temperature	T _{STG}	-40	+85	°C	Ambient temperature
Relative Humidity	RH		80	%	
Lead Soldering Temperature/Time	Ts		260/10	°C/S	
Fiber bend radius		30		mm	
Fiber yield strength			1	kgf	

Note 1: Beyond the scope of absolute maximum ratings can cause permanent damage to the device. If it has been a long time to use the device in the absolute maximum ratings may affect device reliability.

Electric and Optical Characteristics

(All measurements are at Case temperature of 25 °C ±3 °C , @1310±10nm unless stated otherwise.)

Transmitter Operating Characteristic-Optical, Electrical (1310nm TX)								
Parameter	Symbol	Min	Typical	Max	Units	Notes		
Files Outrout Device	Ро	1.8	2.4	3.8	mW	CW, If=Ith+20mA		
Fiber Output Power	20	1.0			mW	CW, If=Ith+20mA,Tc= +85 °C		
Clana Efficiency	2	0.09	0.12	0.19	W/A	CW		
Slope Efficiency	η	0.05			W/A	CW,Tc= +85 ℃		
Center Wavelength	λ	1290	1310	1330	nm	CW, If=Ith+20mA,Tc=-10~ +85 ℃		
Spectral Width(-20dB)	Δλ		0.3	1.0	nm	CW, If=Ith+20mA,Tc=-10~ +85 ℃		
Side-Mode Suppression Ratio	SMSR	30			dB	CW, If=Ith+20mA,Tc=-10~ +85 °C		
Tracking Error	TE ^[1]	-1.5		1.5	dB	I _M hold@P₀=1.5mW,25°C CW,Tc= -10 ~+85 ℃		
Threshold Current			8	15	mA	CW		
Inresnoid Current	l _{th}		20	35	mA	CW, Tc= +85 °C		
Operating Voltage	VF		1.2	1.7	V	CW		
Monitor Current	Ι _Μ	100		1200	μΑ	CW, If=Ith+20mA,V _{RMP} =1V		
Monitor Dark Current	I _D			100	nA	CW,V _{RMP} =5V		

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LN0311 GPON ONU Tri-OSA

Photodiode Capacitance	С		 20	pF	V _{RMP} =5V,f=1MHz
Rise time	Tr		 150	Ps	Unfilter 20%~80%
Fall time	Tf		 150	Ps	Unfilter 20%~80%
Kink Current	lkink	70	 	mA	Tc=-10~+85℃

Receiver Operating Characteristic-Optical, Electrical (1490nm RX)								
Parameter	Symbol	Min	Typical	Max	Units	Notes		
Operating Wavelength	λ	1480	1490	1550	nm			
Supply Voltage	VCC	3.0	3.3	3.6	V			
Circuit Current	lcc		40	50	mA			
Saturation Power	Psat	-6			dBm	λ=1490nm,DR=2.5Gbps,ER=10dB,		
Sensitivity	Sen.		-33	-31.5	dBm	NRZ,PRBS2 ²³ -1,BER=10 ⁻¹² ,Tc=-10~+85 °C		
Breakdown Voltage	Vbr	38	45	53	V	ld=10 µ A, Vcc off		
Dark Current	Id			20	nA	Vr=Vbr-3V		
Responsivity	R	0.75	0.85		A/W	λ=1490nm,M=1		
-3dB Bandwidth	BW	1.4			GHz	-3dB, RL= 50 Ω		

Receiver Operating Characteristic-Optical, Electrical (1550nm RX)						
Parameter	Symbol	Min	Typical	Max	Units	Notes
Operating Wavelength	λ	1550	1555	1560	nm	
Saturation Power	Psat	3			dBm	Pin=-30dBm,VRP=5V,
Responsivity	R	0.8	0.9		A/W	λ=1550nm
Small Signal Bandwidth	BW	3.0			GHz	-3dB, VRP=12V
Dark Current	I _D			1	nA	VRP = 5 V
Composite Second Order beat	CSO ^[2]			-70	dBc	
Composite Third Order beat	CTB ^[2]			-80	dBc	
Capacitance	С			0.8	PF	VRP=5V,f=1MHz

Other Characteristic-Optical, Electrical							
Parameter	Symbol	Min	Typical	Max	Unit	Notes	
	lk CRT			-45	dB	1310nm/1490nm	
Optical Crosstalk				-45	dB	1310nm/1550nm	

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	RL	12			dB	λ=1310nm
Return Loss		20			dB	λ=1490nm
		20			dB	λ=1550nm
		36			dB	λ=1260 ~1441nm
	lso ^[3]	25			dB	λ=1450nm
Optical Isolation(1490nm RX)		25			dB	λ=1530nm
		36			dB	λ=1539 ~1625nm
		40			dB	λ=1260~1360nm
Optical Isolation(1550nm RX)	lso	35			dB	λ=1480~1500nm
		30			dB	λ= 1575~1625nm
Optical Connector Return loss	ORL	45			dB	
Exterior fiber diameter		0.8	0.9	1.0	mm	70 $^\circ C$ max temperature
Pigtail Length	L	580	610	640	mm	Outline Dimensions[L]

Notes 1:TE=10*log(Pf(Tc)/Pf(25 $^\circ C$)) @ APC with monitor current is constant.

Notes 2:Two-tone test condition : f1=50MHz, f2=505MHz, f1±f2, VRP=-12V,Pavg=0dBm,MI=0.4,Rload=75Ω. Notes 3:Suitable for ITU G 984.5 standard.

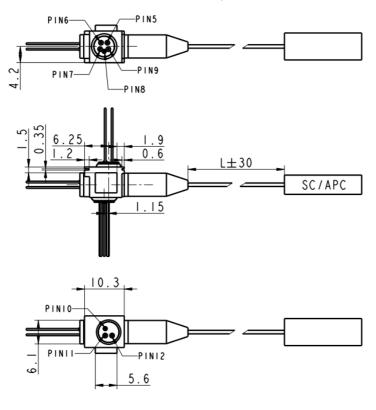
Pigtail parameters

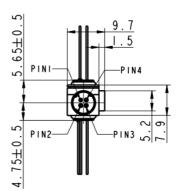
Parameter	Symbol
Optical connector	SC/APC (IEC874/7)
Mode field diameter	9.5±1um
Cladding diameter	125±2um
Outermost Jacket	900±100um
Jacket color	White
Pigtail Length	0.61±0.03m



Outline Dimensions

All dimensions are ±0.1mm unless otherwise specified (Unit: mm). For detail information please contact LinkPhotonic.





Ι	CASE
2	MPD-&LD+
3	MPD+
4	LD-
5	DOUT+
6	DOUT -
7	VAPD
8	GND
9	VCC
10	CASE
	PD-
12	PD+

Precautions

Semiconductor chips are sensitive to electro-static damage. The module shall be packed with antistatic material for transportation. The working station and operators shall be grounded. Switching transients can cause electrical overstress (EOS) damage to the chips. EOS be may resulted from improper ESD handling, improper power sequencing, a faulty power supply or an intermittent connection.

a. Operators should always use antistatic bands and clothing, electric conductive shoes, and other safety appliances while at work are highly recommended.

b. Humidity in working environment should be controlled equal or above 40 percent RH.

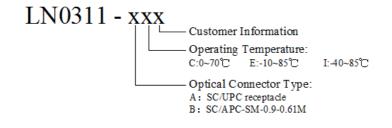
c. It is recommended that grounding mats be placed on the surfaces of assembly line workbench and the surrounding floor in working area, etc.

d. When mounting this product in other parts or materials which can be electrically charged (printed wiring boards, plastic products, etc.), pay close attention to the static electricity in those parts.ESD may damage the product.



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Ordering Information



Statement

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